

| | Type | Hits | Search Text | DBs | Time Stamp |
|---|------|------|---|---|---------------------|
| 1 | IS&R | 7083 | (257/698,752,758,773-776,781,786).CCLS. | USPAT | 2006/03/06 13:33 |
| 2 | IS&R | 4682 | (257/698,752,758,773-776,781,786).CCLS. | US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB | 2006/03/06 15:53 |
| 3 | IS&R | 6046 | (438/612,614,618,622,629,637,639,640,666,668, 672).CCLS. | USPAT | 2006/03/06 16:23 |
| 4 | IS&R | 5852 | (438/612,614,618,622,629,637,639,640,666,668, 672).CCLS. | US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB | 2006/03/06 16:26 |
| 5 | BRS | 1497 | (active transistor gate) and ((bond bonding) near2 (pad)) and ((mesh meshed frame framed) near3 (wire wiring interconnect interconnection layer film)) | USPAT | 2006/03/07 08:24 |
| 6 | BRS | 865 | (active transistor gate) and ((bond bonding) near2 (pad)) and ((mesh meshed frame framed) near3 (wire wiring interconnect interconnection layer film)) | US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB | 2006/03/07 08:25 |